

Longitudinal Proximity Effects in Superconducting Transition-Edge Sensors

John E. Sadleir,^{1,2,*} Stephen J. Smith,² Simon R. Bandler,² James A. Chervenak,² and John R. Clem³

¹*Department of Physics, University of Illinois, 1110 West Green Street, Urbana, IL 61801-3080*

²*NASA Goddard Space Flight Center, 8800 Greenbelt Road, Greenbelt, MD 207701*

³*Ames Laboratory and Department of Physics and Astronomy, Iowa State University, Ames, Iowa, 50011-3160*
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We have found experimentally that the critical current of a square superconducting transition-edge sensor (TES) depends exponentially upon the side length L and the square root of the temperature T . As a consequence, the effective transition temperature T_c of the TES is current-dependent and at fixed current scales as $1/L^2$. We also have found that the critical current can show clear Fraunhofer-like oscillations in an applied magnetic field, similar to those found in Josephson junctions. The observed behavior has a natural theoretical explanation in terms of longitudinal proximity effects if the TES is regarded as a weak link between superconducting leads. We have observed the proximity effect in these devices over extraordinarily long lengths exceeding $100\text{ }\mu\text{m}$.

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A superconductor cooled through its transition temperature T_c while carrying a finite dc bias current undergoes an abrupt decrease in electrical resistance from its normal-state value R_N to zero. Superconducting transition-edge sensors (TESs) exploit this sharp transition; these devices are highly sensitive resistive thermometers used for precise thermal energy measurements.¹ TES microcalorimeters have been developed with measured energy resolutions in the X-ray and gamma-ray band of $\Delta E = 1.8 \pm 0.2\text{ eV}$ FWHM at 6 keV ,² and $\Delta E = 22\text{ eV}$ FWHM at 97 keV ,³ respectively—with the latter result at present the largest reported $E/\Delta E$ of any non-dispersive photon spectrometer. TESs are successfully used across much of the electromagnetic spectrum, measuring the energy of single-photon absorption events from infrared to gamma-ray energies and photon fluxes out to the microwave range.¹ Despite these experimental successes, the dominant physics governing TESs biased in the superconducting phase transition remains poorly understood.¹

To achieve high energy resolution it is important to control both the TES's T_c and its transition width ΔT_c . Because the energy resolution of calorimeters improves with decreasing temperature, they are typically designed to operate at temperatures around 0.1 K . For a TES, this requires a superconductor with T_c in that range. While there exist a few suitable elemental superconductors, the best results have been achieved using proximity-coupled, superconductor/normal-metal (S/N) bilayers^{2,3}, for which T_c is tuned by selection of the thicknesses of the S and N layers.⁴

There have been a variety of models^{4,5,6,7,8} used to explain the noise, T_c , and ΔT_c in TES bilayers, all assuming spatially uniform devices. Though some have been shown to be consistent with certain aspects of particular devices, they do not explain measured T_c and ΔT_c in S/N bilayer TESs generally.

In this paper we emphasize the importance of a phenomenon that so far has been neglected in previous theoretical studies of TESs: the longitudinal proximity effect.

Since the square bilayers at the heart of the TES are connected at opposite ends to superconducting leads with transition temperatures well above the intrinsic transition temperature of the bilayers, superconductivity is induced longitudinally into the bilayers via the proximity effect. As we shall explain later, many of the basic properties of our TES structures are well described by regarding them as SS'S or SN'S weak links.^{9,10,11}

In this paper we report the properties of TESs based on square ($L \times L$) electron-beam-deposited Mo/Au bilayers consisting of 55 nm Mo layers ($T_c \sim 0.9\text{ K}$) to which 210 nm of Au is added. The square side lengths L range from $8\text{ }\mu\text{m}$ to $290\text{ }\mu\text{m}$, and the normal-state resistance per square is $R_N = 17.2 \pm 0.5\text{ m}\Omega$. The bilayers are connected at opposite ends to Mo/Nb leads having measured superconducting transition temperatures of 3.5 and 7.1 K .¹² Further details on the device fabrication process can be found in Ref. 13.

Our measurements are made in an adiabatic demagnetization refrigerator (ADR) with mu-metal and Nb enclosures providing magnetic shielding for the TES devices and SQUID electronics. The magnetic field normal to the TES device plane is controlled by a superconducting coil with the field value determined from the coil geometry and current. Measurements of the TES resistance R are made by applying a sinusoidal current of frequency $5\text{--}10\text{ Hz}$ and amplitude $I_{bias} \sim 50\text{--}250\text{ nA}$, with zero dc component, to the TES in parallel with a $0.2\text{ m}\Omega$ shunt resistor (R_{sh}). The time-dependent TES current is measured with a SQUID feedback circuit with input coil in series with TES. When I_{bias} is less than the TES critical current I_c , R is zero, and all the ac current flows through the TES. However, when $I_{bias} > I_c$ and $R > 0$ during part of the ac cycle, the TES current becomes non-sinusoidal, and its maximum value I becomes less than I_{bias} . The TES resistance R at the TES current I is then determined from $R = R_{sh}(I_{bias} - I)/I$.

The critical current I_c is measured, with the ADR held at constant temperature, by ramping the dc bias current from zero and defining I_c as the TES current at the first

measured finite resistance ($R \sim 10 \mu\Omega$) across the TES. Record averaging is used at higher temperatures where I_c becomes small.

The solid curves in Fig. 1(a) and (b) show measurements of the critical current I_c over seven decades vs temperature T . Note that although we find the intrinsic transition temperature of the Mo/Au bilayer is $T_{cw} = 170.9 \pm 0.1$ mK, at very low currents a zero-resistance state is measured up to much higher temperatures as the TES size is reduced, three times T_{cw} for $L = 8 \mu\text{m}$. On the other hand, for the larger TES sizes ($L=130$ and $290 \mu\text{m}$) the critical current $I_c(T)$ decreases rapidly with T near T_{cw} . The observed I_c behavior as functions of both T and the length L provides strong evidence that our TESs behave as weak-link devices. The dotted curves in (a) and (b) show calculated values of I_c using the Ginzburg-Landau theory described below. In addition, at appropriately chosen temperatures, the critical currents of these devices exhibit Fraunhofer-like oscillations as a function of an applied magnetic field, behavior characteristic of Josephson weak links.^{10,14,15,16} See Fig. 1(c) for an example.

Because I_c depends upon T and L , the effective transition temperature T_c of the TES (the temperature at which an electrical resistance first appears, i.e., $R \sim 10 \mu\Omega$) is both current-dependent and length-dependent. Figure 2(a) exhibits these effects. The points labeled $T_c(I, L)$ are the effective transition temperatures at five different current levels (10 nA to 100 μA) for the data in Fig. 1(a) and (b), showing that $T_c - T_{cw}$ for each current level scales approximately as $1/L^2$ (solid curve fits) for L ranging from 8 to 290 μm . For each L , $T_c - T_{cw}$ depends upon the current.

Also shown in Fig. 2(a) are temperatures $T_{R=0.1 R_N}$ and $T_{R=0.5 R_N}$ for which the resistances are $R = 0.1 R_N$ and $0.5 R_N$, respectively, from which we define $\Delta T_R = T_{0.5 R_N} - T_{0.1 R_N}$. We also define transition widths from the I_c measurements $\Delta T_{c1} = T_{c100\text{nA}} - T_{c10\text{nA}}$ and $\Delta T_{c2} = T_{c1\mu\text{A}} - T_{c10\text{nA}}$. In Fig. 2(b) we show that these three measures of the transition width all vary approximately as $1/L^2$, shown by the dotted line. It also follows that $T_c - T_{cw}$ scales linearly with the transition width.

Weak links in various SS/S or SN/S weak-link structures have been studied experimentally and theoretically by numerous authors. However, here we use a simple version of Ginzburg-Landau (GL) theory^{17,18} to explain the results shown in Figs. 1 and 2. This theory describes the complex order parameter $\psi(\mathbf{r})$, whose absolute square $|\psi(\mathbf{r})|^2$ is the superfluid density in the weak link. We employ the substitution $\psi = \psi_r f e^{i\gamma}$, where ψ_r is the magnitude of the order parameter at the reference points $x = \pm L/2$ adjacent to the leads, $f = |\psi|/\psi_r$ is the normalized order parameter, and γ is the phase. At the reference points, the local value of ψ_r^2 is inversely proportional to the square of the local penetration depth λ_r via $\psi_r^2 = m/4\mu_0 e^2 \lambda_r^2$, and a characteristic reference current density j_r can be defined via $j_r = \phi_0/2\pi\mu_0 \lambda_r^3$, where

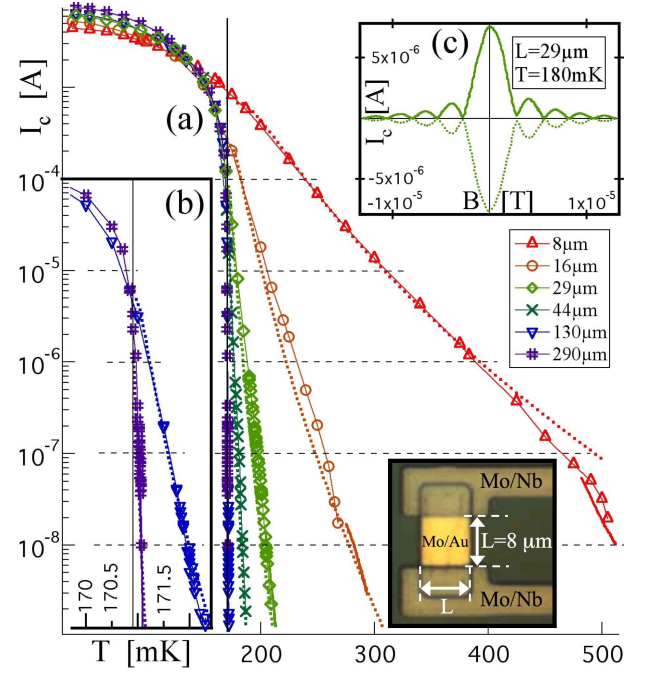


FIG. 1: (Color online) (a) and inset (b) Measured (solid lines and markers) and theoretical (dotted curves) critical current I_c versus temperature T for square TESs with side lengths L ranging from 8 to 290 μm . The bold continuous segments at the lowest currents are obtained by record averaging. The intrinsic transition temperature of the Mo/Au bilayer weak links is $T_{cw} = 170.9 \pm 0.1$ mK (thin vertical lines). For T somewhat larger than T_{cw} , I_c decays approximately exponentially with the square root of $T - T_{cw}$. I_c also depends strongly upon L , which is particularly noticeable for the smaller devices. T and L values of the constant current contours (horizontal dashed lines) are plotted in Fig. 2(a). Inset (c) shows I_c vs applied field for the $L = 29 \mu\text{m}$ device showing Fraunhofer-like oscillations, similar to those seen in Josephson junctions, providing further evidence that the TES exhibits weak-link behavior.

$$\phi_0 = h/2e.$$

Near the center of the weak link, where f becomes very small, the local penetration depth $\lambda = \lambda_r/f$ becomes very large. Moreover, in a thin film of thickness $d < \lambda$, magnetic fields and currents spread out over the two-dimensional screening length (or Pearl length¹⁹) $\Lambda = 2\lambda^2/d = 2\lambda_r^2/df^2$. For all of our samples there is a range of temperatures T far enough above T_{cw} that at the center of the weak link $\Lambda \gg L$ and the current density is $\mathbf{j} = \hat{x}j_x = \hat{x}I/Wd$, where I is the TES current. The first and second GL equations given in Refs. 17 and 18 then depend only upon x and can be written as

$$-f'' + \frac{(t-1)}{\xi_w^2}f + \frac{\kappa^2}{\lambda_r^2}f^3 + \frac{\tilde{j}^2}{\lambda_r^2 f^3} = 0 \quad (1)$$

and

$$\tilde{j} = j_x/j_r = -\lambda_r f^2 (\gamma' + 2\pi A_x/\phi_0), \quad (2)$$

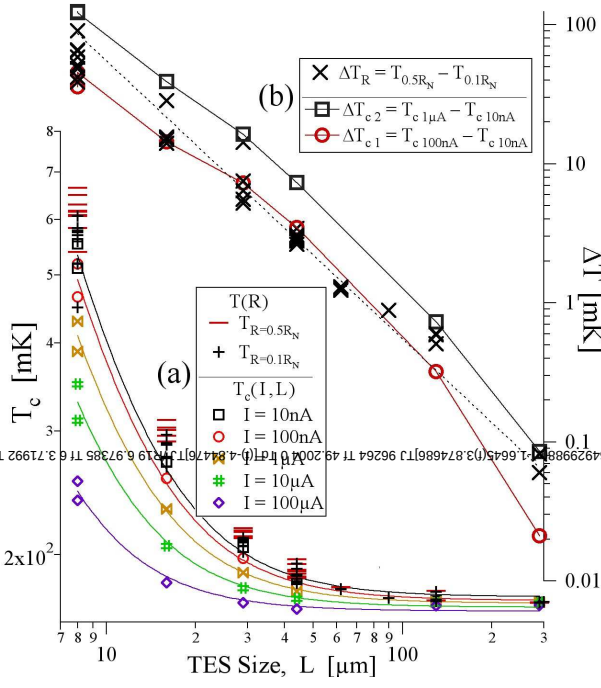


FIG. 2: (a) Measurements of the effective transition temperature T_c at different currents and lengths. Markers $T_c(I, L)$ give the effective T_c from constant current contours of the $I_c(T, L)$ data in Fig. 1, with solid curves being $1/L^2$ fits for each current level. Markers $T(R)$ give temperatures where $R = 0.1 R_N$ and $0.5 R_N$. (b) Three different measures of the transition width defined as differences between pairs of corresponding points shown in (a), as labeled ΔT_R , ΔT_{c1} , and ΔT_{c2} , showing $1/L^2$ scaling (dotted line).

where $t = T/T_{cw}$ is the reduced temperature, $\xi(T) = \xi_w/|t - 1|^{1/2}$ is the temperature-dependent coherence length, κ is the dimensionless Ginzburg-Landau parameter, A_x is the vector potential, and the primes denote derivatives with respect to x .

In this paper we are concerned chiefly with weak-link behavior for which $f(x)$ is an even function of x and has a minimum in the middle of the weak link, $f(0) = f_0$, where $f'(0) = 0$. We can obtain an equation that determines how f_0 depends upon L , t , and $\tilde{j}$ by multiplying Eq. (1) by f' , integrating the result, multiplying by f^2 , and taking the square root, which yields the following equation, valid for $0 \leq x \leq L/2$,

$$df^2/dx = P(f^2), \quad (3)$$

where

$$P(f^2) = \sqrt{2(f^2 - f_0^2) \left[\frac{\kappa^2}{\lambda_r^2} f^4 + \left(\frac{2(t-1)}{\xi_w^2} + \frac{\kappa^2 f_0^2}{\lambda_r^2} \right) f^2 + \frac{2\tilde{j}^2}{\lambda_r^2 f_0^2} \right]}, \quad (4)$$

such that f_0 and $f(x)$ can be obtained from the integrals

$$\int_{f_0^2}^1 \frac{df^2}{P(f^2)} = \frac{L}{2} \quad \text{and} \quad (5)$$

$$\int_{f_0^2}^{f(x)} \frac{df^2}{P(f^2)} = x. \quad (6)$$

The gauge-invariant phase difference across the weak link is²⁰

$$\phi = - \int_{-L/2}^{L/2} \left(\gamma' + \frac{2\pi A_x}{\phi_0} \right) dx = \frac{2\tilde{j}}{\lambda_r} \int_{f_0^2}^1 \frac{df^2}{f^2 P(f^2)}. \quad (7)$$

The integrals in Eqs. (5), (6), and (7) can be evaluated numerically as in Ref. 20 or in terms of elliptic integrals as in Refs. 21 and 22. For given values of λ_r , κ , ξ_w , t , and L , the solutions of Eq. (5) reveal that $\tilde{j}$ is a single-valued function of f_0 .

375 mK. The dotted curves in Fig. 1(a) and (b) show I_c calculated using $\xi_w = 738$ nm and $\lambda_r = 79$ nm in Eq. (9) and Eq. (5), from which f_{00} was obtained.²³

Under conditions for which Eq. (9) is valid, if we define the effective transition temperature $T_c(\tilde{j})$ as the temperature at which the first voltage appears along the length of the TES when it carries a reduced current density $\tilde{j}$, we can determine $T_c(\tilde{j})$ or $t_c(\tilde{j}) = T_c(\tilde{j})/T_{cw}$ by setting $\tilde{j} = \tilde{j}_c$ in Eq. (9) and solving for $t_c(\tilde{j})$, noting that $\xi = \xi_w/\sqrt{t-1}$. The result is

$$(T_c - T_{cw})/T_{cw} = (\xi_w^2/L^2) \ln^2(2f_r^2 \lambda_r \sqrt{t_c - 1}/\tilde{j} \xi_w). \quad (10)$$

Since the dependence upon t_c on the right-hand side is very weak, because it appears within the argument of the logarithm, Eq. (10) predicts that the current-dependent transition temperature of the TES should scale very nearly as $T_c - T_{cw} \propto 1/L^2$ and that T_c should increase as the square of the logarithm of the inverse TES current. Similar reasoning leads to the conclusion that both ΔT_1 and ΔT_2 scale as $1/L^2$. Scaling of ΔT_R can be understood using a simple model of the resistive transition based on the assumption that $R = (2x_j/L)R_N$, where, for a given reduced current density $\tilde{j}$, x_j is the solution of $\tilde{j} = (\lambda_r/2\xi)f(0, x_j)^2$.

We conclude that TESs behave as weak links. This conclusion is based on our experimental findings that (a) the critical current at the first onset of a voltage along the length depends exponentially upon the length L and the

square root of the temperature T , (b) both the current-dependent effective transition temperature T_c and the transition width scale as $1/L^2$, and (c) the TESs show clear Fraunhofer oscillations as a function of applied magnetic field, characteristic of Josephson weak links. It follows that the strength of superconducting order is not uniform over the TES. Our findings have implications on TES magnetic field sensitivity, which impacts required limits on ambient magnetic field magnitude and fluctuations in TES applications. Proposed uses of the longitudinal proximity effect for TES applications include (1) tuning the effective T_c of TES arrays by changing L in mask design, which could compensate for bilayer T_{cw} variability¹ and increase yield, and (2) making small TESs consisting of superconducting leads separated by normal metal, such as Au with $T_{cw} = 0$, avoiding the use of S/N bilayers.

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* john.e.sadleir@nasa.gov

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